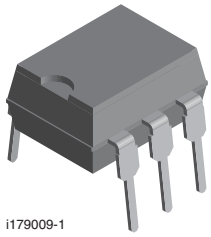
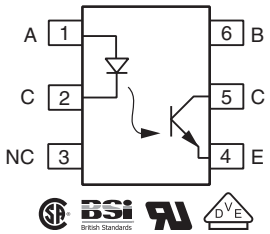
MOC8101, MOC8102, MOC8103, MOC8104, MOC8105

Optocoupler, Phototransistor Output, no Base Connection





FEATURES

- Isolation test voltage, 5300 V_{RMS}
- No base terminal connection for improved common mode interface immunity
- Long term stability
- Industry standard dual in line package
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb-free

e3

RoHS COMPLIANT

DESCRIPTION

The MOC8101, MOC8102, MOC8103, MOC8104, MOC8105 family optocoupler consisting of a gallium arsenide infrared emitting diode optically coupled to a silicon planar phototransistor detector in a plastic plug-in DIP-6 package.

The coupling device is suitable for signal transmission between two electrically separated circuits. The potential difference between the circuits to be coupled should not exceed the maximum permissible reference voltages.

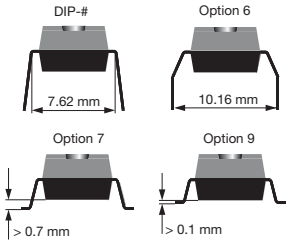
The base terminal of the MOC8101, MOC8102, MOC8103, MOC8104, MOC8105 is not connected, resulting in a substantially improved common mode interference immunity.

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- CSA 93751
- BSI IEC 60950; IEC 60065
- DIN EN 60747-5-5 (VDE 0884) available with option 1

ORDERING INFORMATION

M	O	C	8	1	0	#	-	#	X	0	#	#	T
PART NUMBER								CTR BIN	PACKAGE OPTION				TAPE AND REEL



AGENCY CERTIFIED/PACKAGE	CTR (%)				
	10 mA				
UL, CSA, BSI	**50 to 80**	**73 to 117**	**108 to 173**	**160 to 256**	**65 to 133**
DIP-6	MOC8101	MOC8102	MOC8103	MOC8104	MOC8105
DIP-6, 400 mil, option 6	-	MOC8102-X006	-	-	-
SMD-6, option 9	MOC8101-X009	MOC8102-X009	-	-	-
VDE, UL, CSA, BSI	**50 to 80**	**73 to 117**	**108 to 173**	**160 to 256**	**65 to 133**
DIP-6	MOC8101-X001	-	MOC8103-X001	-	-
DIP-6, 400 mil	-	MOC8102-X016	-	MOC8104-X016	-
SMD-6, option 7	MOC8101-X017T	MOC8102-X017T	-	-	-
SMD-6, option 9	-	-	-	MOC8104-X019T	-

Note

- Additional options may be possible, please contact sales office.

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
INPUT				
Reverse voltage		V_R	6.0	V
Forward continuous current		I_F	60	mA
Surge forward current	t ≤ 10 µs	I_{FSM}	2.5	A
Power dissipation		P_{diss}	100	mW
Derate linearly from 25°C			1.33	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV_{CEO}	30	V
Emitter collector breakdown voltage		BV_{ECO}	7.0	V
Collector current		I_C	50	mA
Derate linearly from 25°C			2.0	mW/°C
Power dissipation		P_{diss}	150	mW
COUPLER				
Isolation test voltage		V_{ISO}	5300	V_{RMS}
Creepage distance			≥ 7.0	mm
			8.0 (2)	mm
Clearance distance			≥ 7.0	mm
			8.0 (2)	mm
Isolation thickness between emitter and detector			≥ 0.4	mm
Comparative tracking index per DIN IEC 112/VDE 0303, part 1		CTI	175	
Isolation resistance	V_{IO} = 500 V	R_{IO}	10^{12}	Ω
Derate linearly from 25 °C			3.33	mW/°C
Total power dissipation		P_{tot}	250	mW
Storage temperature		T_{stg}	- 55 to + 150	°C
Operating temperature		T_{amb}	- 55 to + 100	°C
Junction temperature		T_j	100	°C
Soldering temperature (1)	max. 10 s, dip soldering: distance to seating plane ≥ 1.5 mm	T_{sld}	260	°C

Notes
- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

(2) Applies to wide bending option 6.

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT							
Forward voltage	I_F = 10 mA		V_F		1.25	1.5	V
Breakdown voltage	I_R = 10 µA		V_{BR}	6.0			V
Reverse current	V_R = 6.0 V		I_R		0.01	10	µA
Capacitance	V_R = 0 V, f = 1.0 MHz		C_O		25		pF
Thermal resistance			R_{thja}		750		K/W
OUTPUT							
Collector emitter capacitance	V_{CE} = 5.0 V, f = 1.0 MHz		C_{CE}		5.2		pF
Collector emitter dark current	V_{CE} = 10 V, T_{amp} = 25 °C	MOC8101	I_{CEO1}		1.0	50	nA
	V_{CE} = 10 V, T_{amp} = 100 °C	MOC8102	I_{CEO1}		1.0		µA
Collector emitter breakdown voltage	I_C = 1.0 mA		BV_{CEO}	30			V
Emitter collector breakdown voltage	I_E = 100 µA		BV_{ECO}	7.0			V
Thermal resistance			R_{thja}		500		K/W
COUPLER							
Saturation voltage collector emitter	I_F = 5.0 mA		V_{CEsat}		0.25	0.4	V
Coupling capacitance			C_C		0.6		pF

Note
- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Current transfer ratio	V_{CE} = 10 V, I_F = 10 mA	MOC8101	CTR	50		80	%
		MOC8102	CTR	73		117	%
		MOC8103	CTR	108		173	%
		MOC8104	CTR	160		256	%
		MOC8105	CTR	65		133	%

SWITCHING CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Turn-on time	V_{CC} = 10 V, I_C = 2.0 mA, R_L = 100 Ω	t_{on}		3.0		µs
Turn-off time	V_{CC} = 10 V, I_C = 2.0 mA, R_L = 100 Ω	t_{off}		2.3		µs
Rise time	V_{CC} = 10 V, I_C = 2.0 mA, R_L = 100 Ω	t_r		2.0		µs
Fall time	V_{CC} = 10 V, I_C = 2.0 mA, R_L = 100 Ω	t_f		2.0		µs
Cut off frequency		f_{co}		250		kHz

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

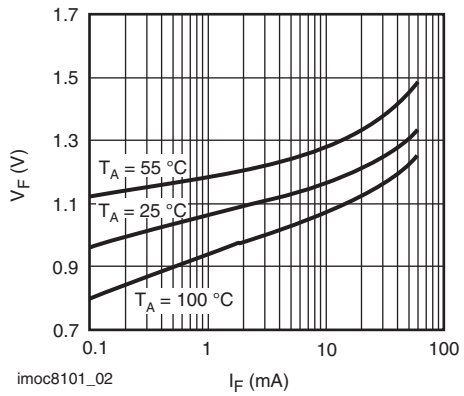


Fig. 1 - Forward Voltage vs. Forward Current

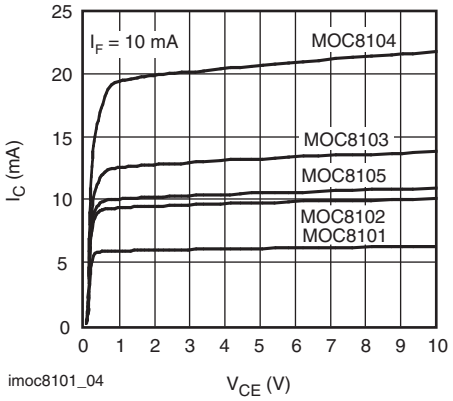


Fig. 3 - Collector Current vs. Collector Emitter Voltage

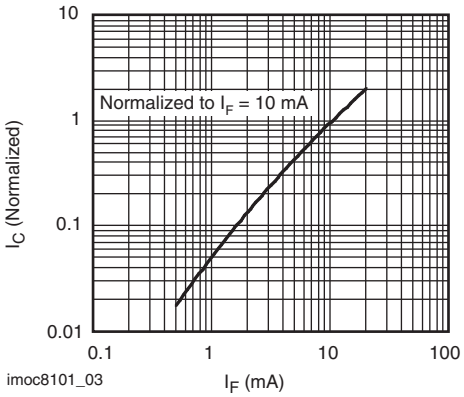


Fig. 2 - Collector Current vs. LED Forward Current

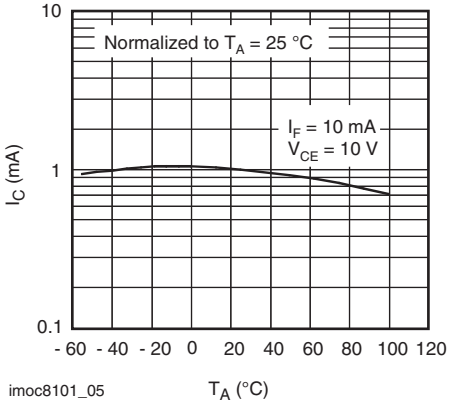


Fig. 4 - Collector Current vs. Ambient Temperature

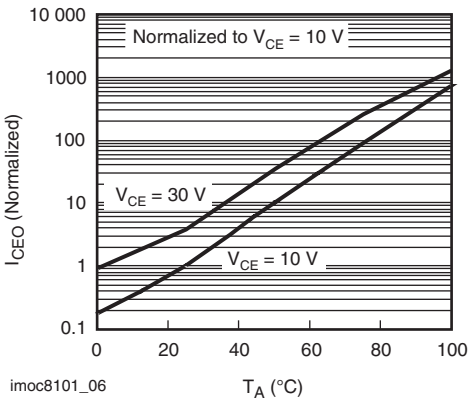


Fig. 5 - Collector Emitter Dark Current vs. Ambient Temperature

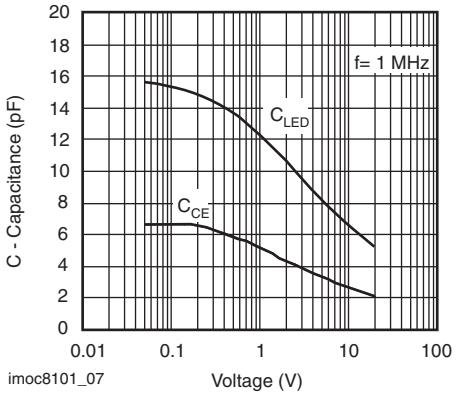


Fig. 6 - Capacitance vs. Voltage

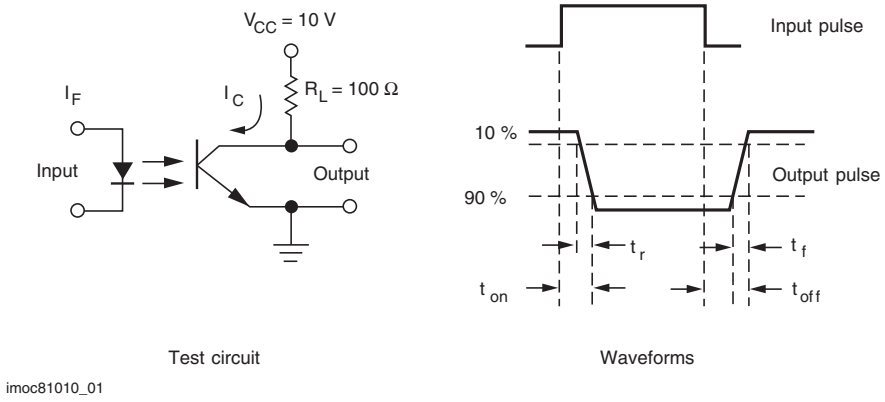
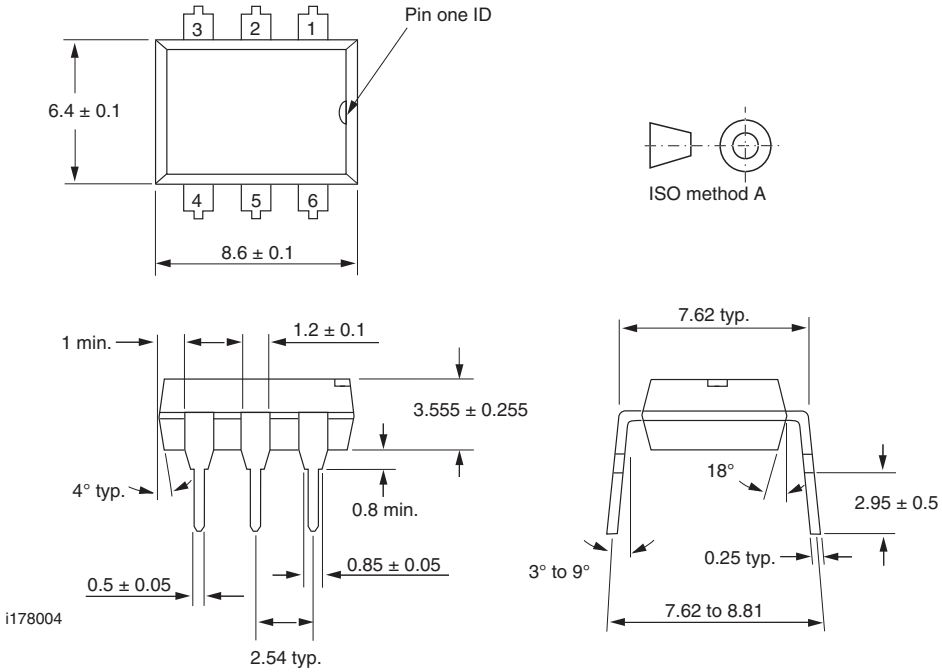
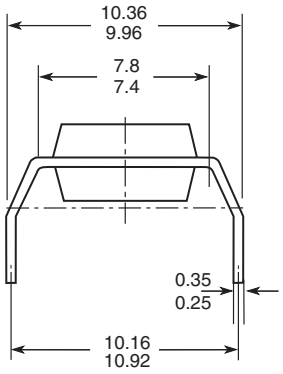


Fig. 7 - Switching Time Test Circuit and Waveforms

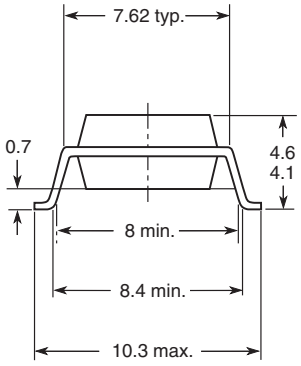
PACKAGE DIMENSIONS in millimeters



Option 6



Option 7



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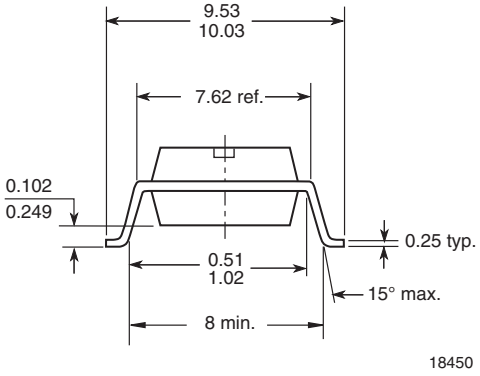
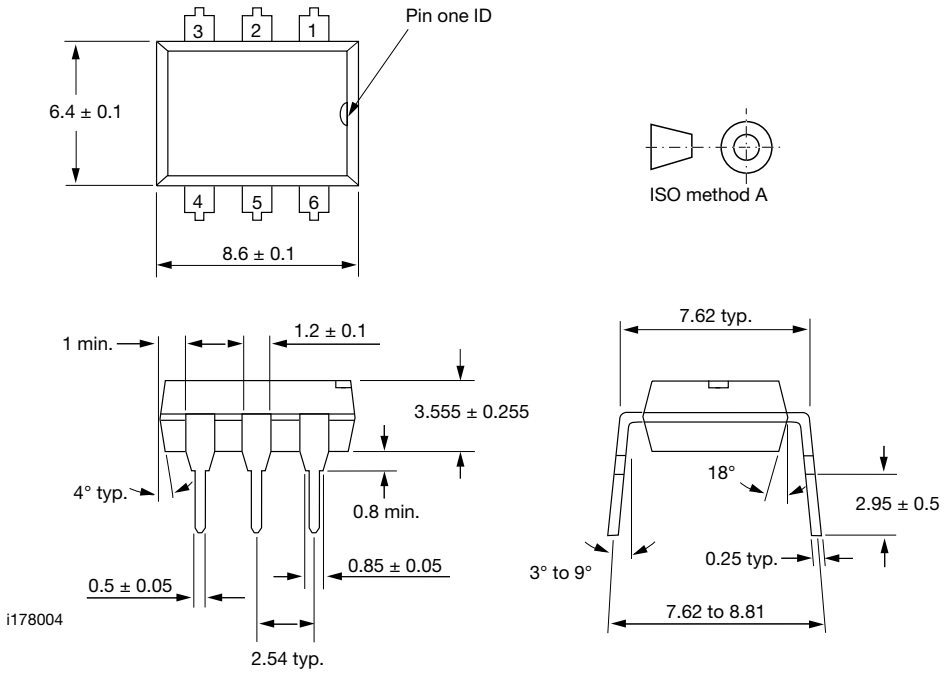


DIP-6A

PACKAGE DIMENSIONS in inches (millimeters)



Note

The information in this document provides generic information but for specific information on a product the appropriate product datasheet should be used.

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